



150V PNP HIGH VOLTAGE TRANSISTOR IN SOT89

Features

- BV_{CEO} > -150V
- I_C = -600mA Continuous Current
- Low Saturation Voltage V_{CE(sat)} < -0.5V @ -50mA
- P_D = 1.2W Power Dissipation
- Complementary part number ZXTN5551Z
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen- and Antimony-Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

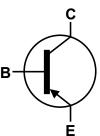
Mechanical Data

- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 3
- Weight: 0.05 grams (Approximate)

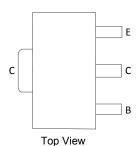




Top View



Device Symbol



Pin Out

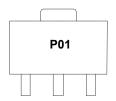
Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
ZXTP5401ZTA	Standard	P01	7	12	1,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



P01 = Product Type Marking Code



Absolute Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-160	V
Collector-Emitter Voltage	V _{CEO}	-150	V
Emitter-Base Voltage	V _{EBO}	-5	V
Continuous Collector Current	Ic	-600	mA
Peak Pulse Collector Current (single pulse)	I _{CM}	-2	Α

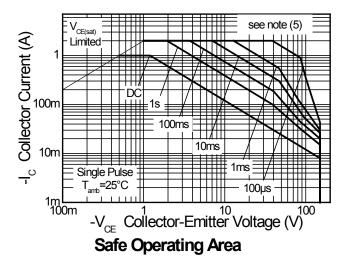
Thermal Characteristics (@ T_A = +25°C, unless otherwise specified.)

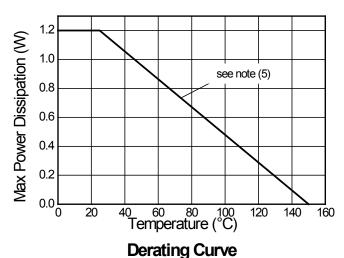
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P_{D}	1.2	W
Linear Derating Factor	_	9.6	mW/°C
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	_	°C/W
Operating and Storage Temperature Range	$T_{J_i}T_{STG}$	-55 to +150	°C

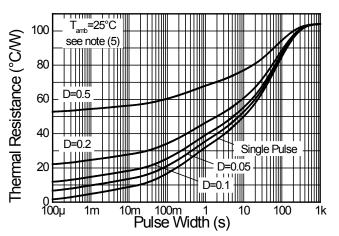
Note: 5. For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz weight copper, in still air conditions.

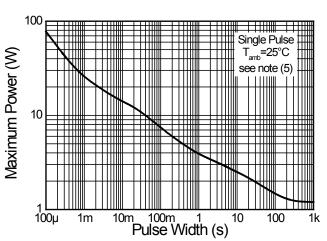


Thermal Characteristics and Derating Information









Transient Thermal Impedance

Pulse Power Dissipation



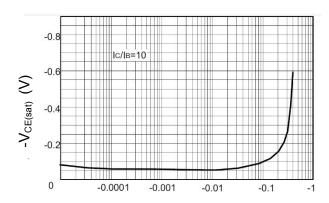
Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-160	-270	_	V	I _C = -100μA
Collector-Emitter Breakdown Voltage	BV _{CEO}	-150	-240	_	V	I _C = -1mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-5	-8.1	_	V	I _E = -100μA
Collector Cut-Off Current	I _{CBO}	_	-1 —	-50 -50	nA μA	V _{CB} = -120V V _{CB} = -120V, T _A = +100°C
Collector-Emitter Saturation Voltage (Note 6)	V _{CE(sat)}	_	-50 -70	-200 -500	mV mV	I_{C} = -10mA, I_{B} = -1mA I_{C} = -50mA, I_{B} = -5mA
Base-Emitter Saturation Voltage (Note 6)	$V_{BE(sat)}$	_	-700 -750	-1000 -1000	mV mV	I_{C} = -10mA, I_{B} = -1mA I_{C} = -50mA, I_{B} = -5mA
DC current gain (Note 6)	h _{FE}	50 60 50	135 135 130	 240 	_	I_{C} = -1mA, V_{CE} = -5V I_{C} = -10mA, V_{CE} = -5V I_{C} = -50mA, V_{CE} = -5V
Transitional frequency	f _T	_	100	_	MHz	$I_C = -10 \text{mA}, V_{CE} = -10 \text{V},$ f = 100MHz
Output Capacitance	C _{obo}	_	_	6	pF	V _{CB} = -10V, f = 1MHz
Delay time	t _d	_	386	_	ns	
Rise time	t _r	_	202	_	ns	$V_{CC} = -10V, I_{C} = -100mA,$
Storage time	ts	_	1720	_	ns	$I_{B1} = -I_{B2} = -10$ mA
Fall time	t _f	_	275		ns	

Note: 6. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

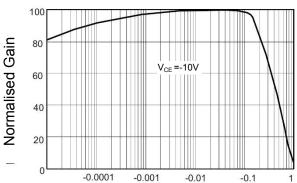


Typical Electrical Characteristics (@ TA = +25°C, unless otherwise specified.)



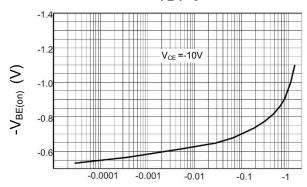
-I_C Collector Current (A)



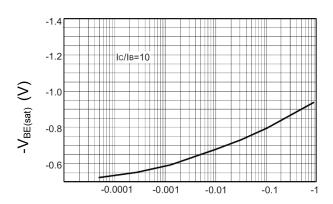


-I_C Collector Current (A)

$h_{FE\,V}\,I_C$



-I_C Collector Current (A) **V**_{BE(on) V} I_C



-I_C Collector Current (A)

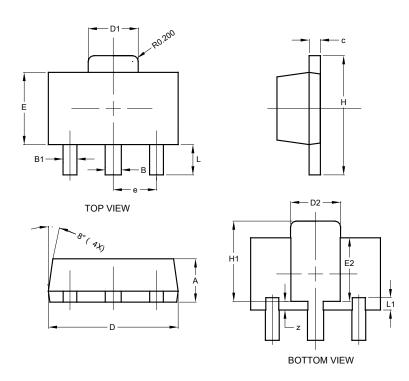
 $V_{\text{BE(sat)} V} I_{\text{C}}$



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89

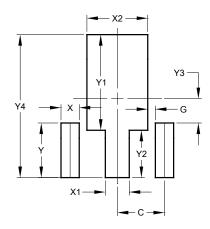


SOT89					
Dim	Min	Max	Тур		
Α	1.40	1.60	1.50		
В	0.50	0.62	0.56		
B1	0.42	0.54	0.48		
С	0.35	0.43	0.38		
D	4.40	4.60	4.50		
D1	1.62	1.83	1.733		
D2	1.61	1.81	1.71		
Е	2.40	2.60	2.50		
E2	2.05	2.35	2.20		
е	-	ı	1.50		
Н	3.95	4.25	4.10		
H1	2.63	2.93	2.78		
L	0.90	1.20	1.05		
L1	0.327	0.527	0.427		
Z	0.20	0.40	0.30		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89



Dimensions	value		
Dilliensions	(in mm)		
С	1.500		
G	0.244		
Х	0.580		
X1	0.760		
X2	1.933		
Υ	1.730		
Y1	3.030		
Y2	1.500		
Y3	0.770		
Y4	4.530		



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